TOSHIBA Field Effect Transistor Silicon N Channel MOS Type (π-MOSV)

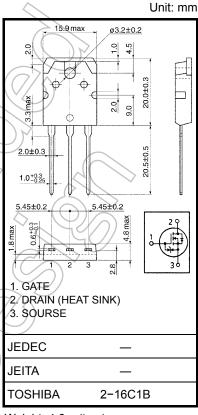
# 2SK2744

Chopper Regulator, DC-DC Converter and Motor Drive Applications

- 4-V gate drive
- Low drain-source ON resistance:  $R_{DS(ON)} = 15 \text{ m}\Omega$  (typ.)
- High forward transfer admittance: |Y<sub>fS</sub>| = 27 S (typ.)
- Low leakage current: I<sub>DSS</sub> = 100 μA (max) (V<sub>DS</sub> = 50 V)
- Enhancement mode:  $V_{th}$  = 1.5 to 3.5 V ( $V_{DS}$  = 10 V,  $I_D$  = 1 mA)

### Absolute Maximum Ratings (Ta = 25°C)

Characteristics		Symbol	Rating	Unit	
Drain-source voltage		$V_{DSS}$	50	V	
Drain-gate voltage ( $R_{GS} = 20 \text{ k}\Omega$ )		$V_{DGR}$	50	V	
Gate-source voltage		$V_{GSS}$	±20	> v	
Drain current	DC (Note 1)	ΙD	45	Α	
	Pulse (Note 1)	I <sub>DP</sub>	180	A	
Drain power dissipation	(Tc = 25°C)	PD	125	/ (w	
Single pulse avalanche	energy (Note 2)	EAS	95	mJ	
Avalanche current		JAR	45	A	
Repetitive avalanche e	nergy (Note 3)	EAR	12.5	μJ	
Channel temperature	(1	Tch	150	,e	
Storage temperature ra	inge	T <sub>stg</sub>	-55 to 150	<b>∵</b> °C	



Weight: 4.6 g (typ.)

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

#### **Thermal Characteristics**

Characteristics	Symbol	Max	Unit
Thermal resistance, channel to case	R <sub>th (ch-c)</sub>	1.0	°C/W
Thermal resistance, channel to ambient	R <sub>th (ch-a)</sub>	50	°C/W

Note 1: Ensure that the channel temperature does not exceed 150°C.

Note 2:  $V_{DD} = 25~V,~T_{ch} = 25^{\circ}C$  (initial),  $L = 58~\mu H,~R_G = 25~\Omega,~I_{AR} = 45~A$ 

Note 3: Repetitive rating: pulse width limited by maximum junction temperature

This transistor is an electrostatic-sensitive device. Please handle with caution.

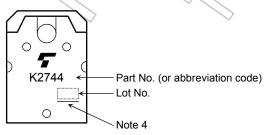
### **Electrical Characteristics (Ta = 25°C)**

Chara	acteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage curr	rent	I <sub>GSS</sub>	$V_{GS} = \pm 16 \text{ V}, V_{DS} = 0 \text{ V}$	_	_	±10	μΑ
Drain cut-off curre	ent	I <sub>DSS</sub>	V <sub>DS</sub> = 50 V, V <sub>GS</sub> = 0 V	_	_	100	μА
Drain-source brea	akdown voltage	V (BR) DSS	I <sub>D</sub> = 10 mA, V <sub>GS</sub> = 0 V	50	_	_	V
Gate threshold vo	ltage	V <sub>th</sub>	V <sub>DS</sub> = 10 V, I <sub>D</sub> = 1 mA	1.5	_	3.5	V
Drain-source ON	resistance	R <sub>DS</sub> (ON)	V <sub>GS</sub> = 10 V, I <sub>D</sub> = 25 A	1	) 15	20	mΩ
Forward transfer	admittance	Y <sub>fs</sub>	V <sub>DS</sub> = 10 V, I <sub>D</sub> = 25 A	15	27	_	S
Input capacitance		C <sub>iss</sub>		))	2300	_	pF
Reverse transfer capacitance		C <sub>rss</sub>	$V_{DS} = 10 \text{ V}, V_{GS} = 0 \text{ V}, f = 1 \text{ MHz}$		420	_	pF
Output capacitance		C <sub>oss</sub>		<sup>7</sup> —	1200	_	pF
Switching time	Rise time	t <sub>r</sub>	10 V ID = 25 A	30	//>		
	Turn-on time	t <sub>on</sub>	VGS VOUT	-	45	> _	ns
	Fall time	t <sub>f</sub>	V <sub>DD</sub> ≈ 25 V		80	_	
	Turn-off time	t <sub>off</sub>	Duty ≤1%, t <sub>w</sub> = 10 μs		230		
Total gate charge Qg (gate-source plus gate-drain)		Von 240 V Von 240 V In 245 A	_	68		nC	
Gate-source charge Q <sub>g</sub>		Qgs	$V_{DD} \approx 40 \text{ V}, V_{GS} = 10 \text{ V}, I_D = 45 \text{ A}$		20		nC
Gate-drain ("miller") charge Q <sub>Q</sub>		Q <sub>gd</sub>			48		nC

## Source-Drain Ratings and Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Continuous drain reverse current (Note 1)	⊃ I <sub>DR</sub>	<u> </u>	ı	-	45	Α
Pulse drain reverse current (Note 1)	I <sub>DRP</sub>	_	١		180	А
Forward voltage (diode)	VDSF	$I_{DR} = 45 \text{ A}, V_{GS} = 0 \text{ V}$	_		-1.8	٧
Reverse recovery time	trr	I <sub>DR</sub> = 45 A, V <sub>GS</sub> = 0 V		130	_	ns
Reverse recovery charge	Qrr	dI <sub>DR</sub> /dt = 50 A/μs	_	0.3	_	μС





Note 4: A line under a Lot No. identifies the indication of product Labels.

Not underlined: [[Pb]]/INCLUDES > MCV Underlined: [[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]]

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